Rashba and other spin-orbit interactions

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Central Themes

- Spin Qubit spin-dependent interactions
- •Spin-Orbit free electrons
- •Spin-Orbit Confined Electrons (Rashba Interaction)
- Condensed Matter Systems
- Electrons on He Rashba Interaction
- •Spin-Orbit Coupling ripplons
- •Electron-Electron Interactions

Electron spin qubits on the He-4/vacuum interface



Decoherence ? Spin-orbit effects ?

Spin-orbit interactions

Free relativistic electron

 $2mc^2$

mc² l+U(r)	c σ∙p
c σ∙p	-mc² l+U(r)

Expansion in p/mc

$$H = \frac{p^2}{2m} + U(\vec{r}) + \frac{e\hbar}{2mc}\vec{H}\vec{\sigma} + \frac{\hbar\vec{\sigma}\cdot[\vec{p}\times\vec{\nabla}U]}{4m\cdot mc^2}$$

Spin-orbit interactions Confined electrons



Dirac Hamiltonian

The same U acts on electrons and positrons

$$H = \frac{p^2}{2m} + U(\vec{r}) + \frac{e\hbar}{2mc}\vec{H}\vec{\sigma} + \int \Psi^*(z)\frac{\hbar\vec{\sigma}\cdot[\vec{p}\times\vec{\nabla}U]}{4m\cdot mc^2}\Psi(z)dz$$

Spin-orbit interactions
Confined electrons

$$\frac{[\vec{p} \times \vec{\sigma}]\hbar}{4m \cdot mc^{2}} \cdot \int \Psi^{*}(z) \vec{\nabla} U \Psi(z) dz$$

$$\nabla U = -i[H, p_{z}] = -i\left[U, -i\frac{\partial}{\partial z}\right] = -i(Hp_{z} - p_{z}H)$$

$$\int \Psi^{*}(z) \vec{\nabla} U \Psi(z) dz = -i\int \Psi^{*}(z)(Hp_{z} - p_{z}H)\Psi(z) dz$$

 $\Psi^*H = E\Psi^*; H\Psi = E\Psi$

Ehrenfest theorem

$$\frac{[\vec{p} \times \vec{\sigma}]\hbar}{4m \cdot mc^2} \int \Psi^*(z) \vec{\nabla} U \Psi(z) dz = 0 \qquad \blacksquare$$

Spin-orbit interactions Condensed Matter systems



ms² I+U ₁ (r)+ eE r	s σ∙p
s σ·p	-ms² I+U ₂ (r) + eE r



Different offsets, different barriers For conduction and valence electrons or ground s and excited p states

Spin-orbit interactions Condensed Matter systems





Different offsets in conduction and valence bands

Lassnig (1985)

Rashba type spin-orbit interaction He



- Penetration into He
- Excited p-state
- Different parameters of quantized state in s and p-state
- $E_g = 50 \text{ eV}$, $s = 2.7 \times 10^8 \text{ cm/s}$
- m free electron mass

$$H_{so} = \alpha \frac{\hbar \vec{\sigma} \cdot [\vec{p} \times e\overline{E}]}{4m \cdot ms^2}$$

Order of magnitude stronger than relativistic spin-orbit term. T₁= 1s (τ =100ns)

Lateral confinement

All discrete levels; no k



Capillary waves - ripplons

Thermally excited height variations of the helium surface $\delta(ec{r},t)$

 \vec{r} 2D in-plane coordinate

 $U(\vec{r}) = eE\delta(\vec{r},t)$ Spectrum $\omega^2 = (\sigma/\rho)k^3$

Spin relaxation in a He surface quantum dot



Up and down spins are described by the same (blue) orbital wavefunction

Admixture by Rashba term to red state (different lateral orbital wavefunction

Ripplon
$$T_1 = 10^6 s$$

For inelastic [processes, acoustic phonons are more important

Other spin-orbit interactions

Capillary waves - ripplons

Thermally excited height variations of the helium surface $\delta(ec{r},t)$

$$\vec{r}$$
 2D in-plane coordinate

 $U(\vec{r}) = eE\delta(\vec{r}, t) \qquad \text{Spectrum} \qquad \omega^2 = (\sigma / \rho)k^3$ $H_{so} = \alpha \frac{\hbar \vec{\sigma} \cdot [\vec{p} \times \vec{\nabla} U]}{4m \cdot ms^2}$

E – total electric field in z=direction

Spin-orbit interactions with ripplons

ms² l+U(r, t)	s σ·p
s σ·p	-ms² l+αU(r, t)

$$H_{so} = \alpha e E \delta \frac{\hbar \vec{\sigma} \cdot [\vec{p} \times \vec{k}]}{4m \cdot ms^2}$$

Magnitude: $\boldsymbol{\delta}$ is the average mean displacement

k is the transferred wavevector

Ripplon coupling limits mobility (μ = 10⁸ cm² /V s)

$$H_{so} = eE\delta \frac{\hbar \cdot \sigma_z [\vec{p} \times \vec{k}]_z}{4m \cdot ms^2} \alpha$$

Only in-plane wavevectors

Spin-orbit interactions with ripplons

$$H_{so} = \alpha e E \delta \frac{\hbar \cdot \sigma_z [\vec{p} \times \bar{k}]_z}{4m \cdot ms^2}$$

 S_z is not affected , no spin relaxation

 S_x , S_y are affected, hence spin dephasing (decoherence)

Spin dephasing times $0.1\alpha^{-2}$ s

Corresponds to momentum relaxation τ =100ns

Lateral confinement

$$H_{so} = \frac{\hbar \vec{\sigma} \cdot [\vec{p} \times \vec{\nabla} U]}{4m \cdot ms^2}$$



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Direct spin-ripplon coupling to Each of the excited level

 $T_2 = 10^2 s$

Virtual escape of electron from the dot

Other spin-orbit interactions

Solids : interaction of spin of one electron with an orbital motion of another electron

 $H_s^{(3)} = -\frac{e^2 2P^2}{\kappa} \frac{\Delta(2E_g + \Delta)}{(E_g + \Delta)^2} \times [(\mathbf{r} \times \hat{\mathbf{p}}_1) \cdot \mathbf{S}_1 - (\mathbf{r} \times \hat{\mathbf{p}}_2) \cdot \mathbf{S}_2]/\hbar^2 r^3.$

Breit –Landau term in two-electron Dirac Model

Electron-electron Interactions contribute to relaxation and dephasing

Conclusions

- In 2D, Rashba interaction is present
- Coupling with ripplons is more important
- Spin dephasing times shorter than spin relaxation times
- •Spin-orbit terms in electron-electron interactions